



HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

AP2121

General Description

The AP2121 series are positive voltage regulator ICs fabricated by CMOS process. Each of these ICs consists of a voltage reference, an error amplifier, a resistor network for setting output voltage, a current limit circuit for current protection and a chip-enable circuit (5-pin products only).

The AP2121 series feature high supply voltage ripple rejection, low dropout voltage, low noise, high output voltage accuracy, and low current consumption which make them ideal for use in various battery-powered devices.

The AP2121 series have 1.2V, 1.3V, 1.5V, 1.8V, 2.5V, 2.8V, 3.0V, 3.2V and 3.3V versions.

The AP2121 are available in standard SOT-23-3 and SOT-23-5 packages.

Features

- Low Dropout Voltage at $I_{OUT}=100mA$: 150mV Typical (Except 1.2V, 1.3V and 1.5V Versions)
- Low Standby Current: 0.1 μA Typical
- Low Quiescent Current: 25 μA Typical
- High Ripple Rejection: 70dB Typical ($f=1kHz$)
- Output Current: More Than 200mA (300mA Limit)
- Extremely Low Noise: 30 μV_{rms} (10Hz to 100kHz)
- Excellent Line Regulation: 4mV Typical
- Excellent Load Regulation: 12mV Typical
- High Output Voltage Accuracy: $\pm 2\%$
- Excellent Line Transient Response and Load Transient Response
- Compatible with Low ESR Ceramic Capacitor (as Low as 1 μF)

Applications

- Mobile Phones, Cordless Phones
- Wireless Communication Equipment
- Portable Games
- Cameras, Video Recorders
- Sub-board Power Supplies for Telecom Equipment
- Battery Powered Equipment

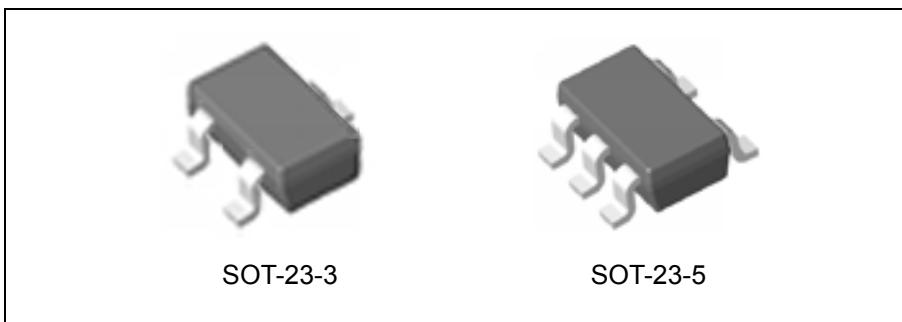


Figure 1. Package Types of AP2121

HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

AP2121

Pin Configuration

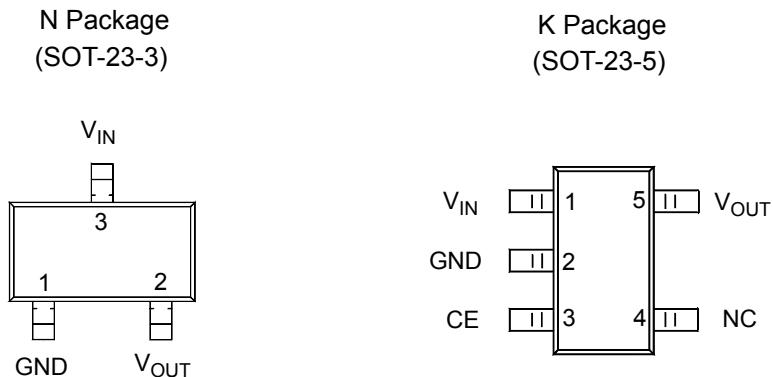
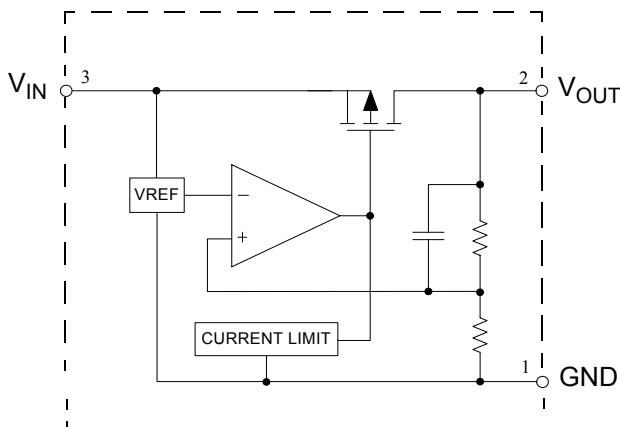


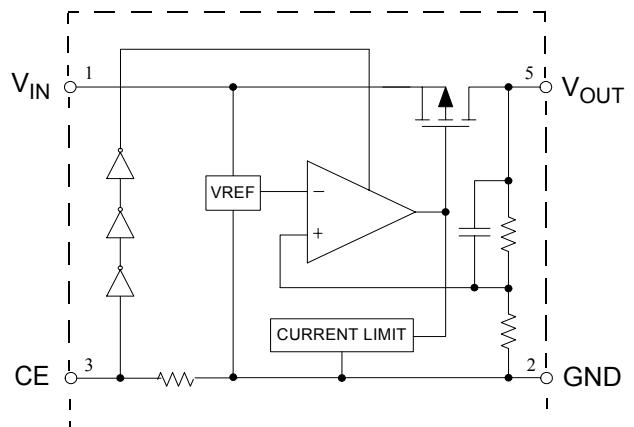
Figure 2. Pin Configuration of AP2121 (Top View)

Pin Description

Pin Number		Pin Name	Function
SOT-23-3	SOT-23-5		
3	1	V _{IN}	Input voltage
1	2	GND	Ground
	3	CE	Active high enable input pin. Logic high=enable, logic low=shutdown
	4	NC	No connection
2	5	V _{OUT}	Regulated output voltage

HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR**AP2121****Functional Block Diagram**

SOT-23-3



SOT-23-5

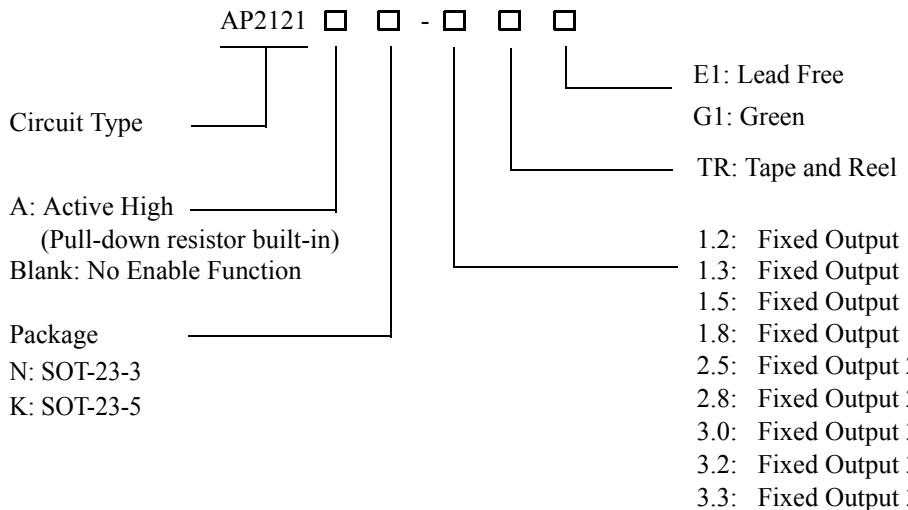
Figure 3. Functional Block Diagram of AP2121



HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

AP2121

Ordering Information



Package	Temperature Range	Condition	Part Number		Marking ID		Packing Type
			Lead Free	Green	Lead Free	Green	
SOT-23-3	-40 to 85°C		AP2121N-1.2TRE1	AP2121N-1.2TRG1	EF9	GF9	Tape & Reel
			AP2121N-1.3TRE1	AP2121N-1.3TRG1	EG9	GG9	Tape & Reel
			AP2121N-1.5TRE1	AP2121N-1.5TRG1	EF1	GF1	Tape & Reel
			AP2121N-1.8TRE1	AP2121N-1.8TRG1	EF3	GF3	Tape & Reel
			AP2121N-2.5TRE1	AP2121N-2.5TRG1	EF4	GF4	Tape & Reel
			AP2121N-2.8TRE1	AP2121N-2.8TRG1	EF5	GF5	Tape & Reel
			AP2121N-3.0TRE1	AP2121N-3.0TRG1	EF6	GF6	Tape & Reel
			AP2121N-3.2TRE1	AP2121N-3.2TRG1	EF7	GF7	Tape & Reel
			AP2121N-3.3TRE1	AP2121N-3.3TRG1	EF8	GF8	Tape & Reel
SOT-23-5	-40 to 85°C	Active High (Pull-down resistor built-in)	AP2121AK-1.2TRE1	AP2121AK-1.2TRG1	E1T	G1T	Tape & Reel
		Active High (Pull-down resistor built-in)	AP2121AK-1.3TRE1	AP2121AK-1.3TRG1	E1R	G1R	Tape & Reel
		Active High (Pull-down resistor built-in)	AP2121AK-1.5TRE1	AP2121AK-1.5TRG1	E1Z	G1Z	Tape & Reel
		Active High (Pull-down resistor built-in)	AP2121AK-1.8TRE1	AP2121AK-1.8TRG1	E1U	G1U	Tape & Reel
		Active High (Pull-down resistor built-in)	AP2121AK-2.5TRE1	AP2121AK-2.5TRG1	E1V	G1V	Tape & Reel
		Active High (Pull-down resistor built-in)	AP2121AK-2.8TRE1	AP2121AK-2.8TRG1	E1W	G1W	Tape & Reel
		Active High (Pull-down resistor built-in)	AP2121AK-3.0TRE1	AP2121AK-3.0TRG1	E1X	G1X	Tape & Reel
		Active High (Pull-down resistor built-in)	AP2121AK-3.2TRE1	AP2121AK-3.2TRG1	E3Z	G3Z	Tape & Reel
		Active High (Pull-down resistor built-in)	AP2121AK-3.3TRE1	AP2121AK-3.3TRG1	E1Y	G1Y	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green packages.



HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

AP2121

Absolute Maximum Ratings (Note 1)

Parameter	Symbol	Value		Unit
Input Voltage	V _{IN}	6.5		V
Enable Input Voltage	V _{CE}	-0.3 to V _{IN} +0.3		V
Output Current	I _{OUT}	300		mA
Junction Temperature	T _J	150		°C
Storage Temperature Range	T _{STG}	-65 to 150		°C
Lead Temperature (Soldering, 10sec)	T _{LEAD}	260		°C
Thermal Resistance (Junction to Ambient) (Note 2)	θ _{JA}	SOT-23-3	250	°C/W
		SOT-23-5	250	
ESD (Human Body Model)	ESD	2000		V
ESD (Machine Model)	ESD	200		V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Note 2: Absolute maximum ratings indicate limits beyond which damage to the component may occur. Electrical specifications do not apply when operating the device outside of its operating ratings. The maximum allowable power dissipation is a function of the maximum junction temperature, T_{J(max)}, the junction-to-ambient thermal resistance, θ_{JA}, and the ambient temperature, T_A. The maximum allowable power dissipation at any ambient temperature is calculated using: P_{D(max)}=(T_{J(max)} - T_A)/θ_{JA}. Exceeding the maximum allowable power dissipation will result in excessive die temperature.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Input Voltage	V _{IN}	2	6	V
Operating Junction Temperature Range	T _J	-40	85	°C



HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

AP2121

Electrical Characteristics

AP2121-1.2 Electrical Characteristics

(V_{IN}=2.2V, T_J=25°C, C_{IN}=1μF, C_{OUT}=1μF, **Bold** typeface applies over -40°C≤T_J≤85°C, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	V _{OUT}	V _{IN} =2.2V 1mA≤I _{OUT} ≤30mA	1.176	1.2	1.224	V
Input Voltage	V _{IN}				6	V
Output Current	I _{OUT}	V _{IN} -V _{OUT} =1V	200			mA
Load Regulation	V _{RLOAD}	V _{IN} =2.2V 1mA≤I _{OUT} ≤80mA		12	40	mV
Line Regulation	V _{RLINE}	2.2V≤V _{IN} ≤6V I _{OUT} =30mA		4	16	mV
Dropout Voltage	V _{DROP}	I _{OUT} =10mA		700	900	mV
		I _{OUT} =100mA		700	900	
		I _{OUT} =150mA		700	900	
		I _{OUT} =200mA		700	900	
Quiescent Current	I _Q	V _{IN} =2.2V, I _{OUT} =0mA		25	50	μA
Standby Current	I _{STD}	V _{IN} =2.2V V _{CE} in OFF mode		0.1	1	μA
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p, f=1kHz V _{IN} =2.2V		70		dB
Output Voltage Temperature Coefficient	ΔV _{OUT} /ΔT	I _{OUT} =30mA		±120		μV/°C
	(ΔV _{OUT} /V _{OUT})/ΔT			±100		ppm/°C
Short Current Limit	I _{LIMIT}	V _{OUT} =0V		50		mA
RMS Output Noise	V _{NOISE}	T _A =25°C 10Hz ≤f≤100kHz		30		μVrms
CE "High" Voltage		CE input voltage "High"	1.5			V
CE "Low" Voltage		CE input voltage "Low"			0.25	V
CE Pull-down Resistance	R _{PD}		2.5	5	10	MΩ
Thermal Resistance (Junction to Case)	θ _{JC}	SOT-23-3		74		°C/W
		SOT-23-5		74		



HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

AP2121

Electrical Characteristics (Continued)

AP2121-1.3 Electrical Characteristics

(V_{IN}=2.3V, T_J=25°C, C_{IN}=1μF, C_{OUT}=1μF, **Bold** typeface applies over -40°C≤T_J≤85°C, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	V _{OUT}	V _{IN} =2.3V 1mA≤I _{OUT} ≤30mA	1.274	1.3	1.326	V
Input Voltage	V _{IN}				6	V
Output Current	I _{OUT}	V _{IN} -V _{OUT} =1V	200			mA
Load Regulation	V _{RLOAD}	V _{IN} =2.3V 1mA≤I _{OUT} ≤80mA		12	40	mV
Line Regulation	V _{RLINE}	2.3V≤V _{IN} ≤6V I _{OUT} =30mA		4	16	mV
Dropout Voltage	V _{DROP}	I _{OUT} =10mA		600	800	mV
		I _{OUT} =100mA		600	800	
		I _{OUT} =150mA		600	800	
		I _{OUT} =200mA		600	800	
Quiescent Current	I _Q	V _{IN} =2.3V, I _{OUT} =0mA		25	50	μA
Standby Current	I _{STD}	V _{IN} =2.3V V _{CE} in OFF mode		0.1	1	μA
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p, f=1kHz V _{IN} =2.3V		70		dB
Output Voltage Temperature Coefficient	ΔV _{OUT} /ΔT	I _{OUT} =30mA		±130		μV/°C
	(ΔV _{OUT} /V _{OUT})/ΔT			±100		ppm/°C
Short Current Limit	I _{LIMIT}	V _{OUT} =0V		50		mA
RMS Output Noise	V _{NOISE}	T _A =25°C 10Hz ≤f≤100kHz		30		μVrms
CE "High" Voltage		CE input voltage "High"	1.5			V
CE "Low" Voltage		CE input voltage "Low"			0.25	V
CE Pull-down Resistance	R _{PD}		2.5	5	10	MΩ
Thermal Resistance (Junction to Case)	θ _{JC}	SOT-23-3		74		°C/W
		SOT-23-5		74		



HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

AP2121

Electrical Characteristics (Continued)

AP2121-1.5 Electrical Characteristics

(V_{IN}=2.5V, T_J=25°C, C_{IN}=1μF, C_{OUT}=1μF, **Bold** typeface applies over -40°C≤T_J≤85°C, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	V _{OUT}	V _{IN} =2.5V 1mA≤I _{OUT} ≤30mA	1.47	1.5	1.53	V
Input Voltage	V _{IN}				6	V
Output Current	I _{OUT}	V _{IN} -V _{OUT} =1V	200			mA
Load Regulation	V _{RLOAD}	V _{IN} =2.5V 1mA≤I _{OUT} ≤80mA		12	40	mV
Line Regulation	V _{RLINE}	2.3V≤V _{IN} ≤6V I _{OUT} =30mA		4	16	mV
Dropout Voltage	V _{DROP}	I _{OUT} =10mA		400	600	mV
		I _{OUT} =100mA		400	600	
		I _{OUT} =150mA		400	600	
		I _{OUT} =200mA		400	600	
Quiescent Current	I _Q	V _{IN} =2.5V, I _{OUT} =0mA		25	50	μA
Standby Current	I _{STD}	V _{IN} =2.5V V _{CE} in OFF mode		0.1	1	μA
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p, f=1kHz V _{IN} =2.5V		70		dB
Output Voltage Temperature Coefficient	ΔV _{OUT} /ΔT	I _{OUT} =30mA		±150		μV/°C
	(ΔV _{OUT} /V _{OUT})/ΔT			±100		ppm/°C
Short Current Limit	I _{LIMIT}	V _{OUT} =0V		50		mA
RMS Output Noise	V _{NOISE}	T _A =25°C 10Hz≤f≤100kHz		30		μVrms
CE "High" Voltage		CE input voltage "High"	1.5			V
CE "Low" Voltage		CE input voltage "Low"			0.25	V
CE Pull-down Resistance	R _{PD}		2.5	5	10	MΩ
Thermal Resistance (Junction to Case)	θ _{JC}	SOT-23-3		74		°C/W
		SOT-23-5		74		



HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

AP2121

Electrical Characteristics (Continued)

AP2121-1.8 Electrical Characteristics

(V_{IN}=2.8V, T_J=25°C, C_{IN}=1μF, C_{OUT}=1μF, **Bold** typeface applies over -40°C≤T_J≤85°C, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	V _{OUT}	V _{IN} =2.8V 1mA≤I _{OUT} ≤30mA	1.764	1.8	1.836	V
Input Voltage	V _{IN}				6	V
Output Current	I _{OUT}	V _{IN} -V _{OUT} =1V	200			mA
Load Regulation	V _{RLOAD}	V _{IN} =2.8V 1mA≤I _{OUT} ≤80mA		12	40	mV
Line Regulation	V _{RLINE}	2.3V≤V _{IN} ≤6V I _{OUT} =30mA		4	16	mV
Dropout Voltage	V _{DROP}	I _{OUT} =10mA		20	40	mV
		I _{OUT} =100mA		150	300	
		I _{OUT} =150mA		200	400	
		I _{OUT} =200mA		250	500	
Quiescent Current	I _Q	V _{IN} =2.8V, I _{OUT} =0mA		25	50	μA
Standby Current	I _{STD}	V _{IN} =2.8V V _{CE} in OFF mode		0.1	1	μA
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p, f=1kHz V _{IN} =2.8V		70		dB
Output Voltage Temperature Coefficient	ΔV _{OUT} /ΔT	I _{OUT} =30mA		±180		μV/°C
	(ΔV _{OUT} /V _{OUT})/ΔT			±100		ppm/°C
Short Current Limit	I _{LIMIT}	V _{OUT} =0V		50		mA
RMS Output Noise	V _{NOISE}	T _A =25°C 10Hz ≤f≤100kHz		30		μVrms
CE "High" Voltage		CE input voltage "High"	1.5			V
CE "Low" Voltage		CE input voltage "Low"			0.25	V
CE Pull-down Resistance	R _{PD}		2.5	5	10	MΩ
Thermal Resistance (Junction to Case)	θ _{JC}	SOT-23-3		74		°C/W
		SOT-23-5		74		



HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

AP2121

Electrical Characteristics (Continued)

AP2121-2.5 Electrical Characteristics

(V_{IN}=3.5V, T_J=25°C, C_{IN}=1μF, C_{OUT}=1μF, **Bold** typeface applies over -40°C≤T_J≤85°C, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	V _{OUT}	V _{IN} =3.5V 1mA≤I _{OUT} ≤30mA	2.45	2.5	2.55	V
Input Voltage	V _{IN}				6	V
Output Current	I _{OUT}	V _{IN} -V _{OUT} =1V	200			mA
Load Regulation	V _{RLOAD}	V _{IN} =3.5V 1mA≤I _{OUT} ≤80mA		12	40	mV
Line Regulation	V _{RLINE}	3V≤V _{IN} ≤6V I _{OUT} =30mA		4	16	mV
Dropout Voltage	V _{DROP}	I _{OUT} =10mA		20	40	mV
		I _{OUT} =100mA		150	300	
		I _{OUT} =150mA		200	400	
		I _{OUT} =200mA		250	500	
Quiescent Current	I _Q	V _{IN} =3.5V, I _{OUT} =0mA		25	50	μA
Standby Current	I _{STD}	V _{IN} =3.5V V _{CE} in OFF mode		0.1	1	μA
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p, f=1kHz V _{IN} =3.5V		70		dB
Output Voltage Temperature Coefficient	ΔV _{OUT} /ΔT	I _{OUT} =30mA		±250		μV/°C
	(ΔV _{OUT} /V _{OUT})/ΔT			±100		ppm/°C
Short Current Limit	I _{LIMIT}	V _{OUT} =0V		50		mA
RMS Output Noise	V _{NOISE}	T _A =25°C 10Hz ≤f≤100kHz		30		μVrms
CE "High" Voltage		CE input voltage "High"	1.5			V
CE "Low" Voltage		CE input voltage "Low"			0.25	V
CE Pull-down Resistance	R _{PD}		2.5	5	10	MΩ
Thermal Resistance (Junction to Case)	θ _{JC}	SOT-23-3		74		°C/W
		SOT-23-5		74		



HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

AP2121

Electrical Characteristics (Continued)

AP2121-2.8 Electrical Characteristics

(V_{IN}=3.8V, T_J=25°C, C_{IN}=1μF, C_{OUT}=1μF, **Bold** typeface applies over -40°C≤T_J≤85°C, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	V _{OUT}	V _{IN} =3.8V 1mA≤I _{OUT} ≤30mA	2.744	2.8	2.856	V
Input Voltage	V _{IN}				6	V
Output Current	I _{OUT}	V _{IN} -V _{OUT} =1V	200			mA
Load Regulation	V _{RLOAD}	V _{IN} =3.8V 1mA≤I _{OUT} ≤80mA		12	40	mV
Line Regulation	V _{RLINE}	3.3V≤V _{IN} ≤6V I _{OUT} =30mA		4	16	mV
Dropout Voltage	V _{DROP}	I _{OUT} =10mA		20	40	mV
		I _{OUT} =100mA		150	300	
		I _{OUT} =150mA		200	400	
		I _{OUT} =200mA		250	500	
Quiescent Current	I _Q	V _{IN} =3.8V, I _{OUT} =0mA		25	50	μA
Standby Current	I _{STD}	V _{IN} =3.8V V _{CE} in OFF mode		0.1	1	μA
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p, f=1kHz V _{IN} =3.8V		70		dB
Output Voltage Temperature Coefficient	ΔV _{OUT} /ΔT	I _{OUT} =30mA		±280		μV/°C
	(ΔV _{OUT} /V _{OUT})/ΔT			±100		ppm/°C
Short Current Limit	I _{LIMIT}	V _{OUT} =0V		50		mA
RMS Output Noise	V _{NOISE}	T _A =25°C 10Hz ≤f≤100kHz		30		μVrms
CE "High" Voltage		CE input voltage "High"	1.5			V
CE "Low" Voltage		CE input voltage "Low"			0.25	V
CE Pull-down Resistance	R _{PD}		2.5	5	10	MΩ
Thermal Resistance (Junction to Case)	θ _{JC}	SOT-23-3		74		°C/W
		SOT-23-5		74		



HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

AP2121

Electrical Characteristics (Continued)

AP2121-3.0 Electrical Characteristics

(V_{IN}=4V, T_j=25°C, C_{IN}=1μF, C_{OUT}=1μF, **Bold** typeface applies over -40°C≤T_j≤85°C, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	V _{OUT}	V _{IN} =4V 1mA≤I _{OUT} ≤30mA	2.94	3.0	3.06	V
Input Voltage	V _{IN}				6	V
Output Current	I _{OUT}	V _{IN} -V _{OUT} =1V	200			mA
Load Regulation	V _{RLOAD}	V _{IN} =4V 1mA≤I _{OUT} ≤80mA		12	40	mV
Line Regulation	V _{RLINE}	3.5V≤V _{IN} ≤6V I _{OUT} =30mA		4	16	mV
Dropout Voltage	V _{DROP}	I _{OUT} =10mA		20	40	mV
		I _{OUT} =100mA		150	300	
		I _{OUT} =150mA		200	400	
		I _{OUT} =200mA		250	500	
Quiescent Current	I _Q	V _{IN} =4V, I _{OUT} =0mA		25	50	μA
Standby Current	I _{STD}	V _{IN} =4V V _{CE} in OFF mode		0.1	1	μA
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p, f=1kHz V _{IN} =4V		70		dB
Output Voltage Temperature Coefficient	ΔV _{OUT} /ΔT	I _{OUT} =30mA		±300		μV/°C
	(ΔV _{OUT} /V _{OUT})/ΔT			±100		ppm/°C
Short Current Limit	I _{LIMIT}	V _{OUT} =0V		50		mA
RMS Output Noise	V _{NOISE}	T _A =25°C 10Hz ≤f≤100kHz		30		μVrms
CE "High" Voltage		CE input voltage "High"	1.5			V
CE "Low" Voltage		CE input voltage "Low"			0.25	V
CE Pull-down Resistance	R _{PD}		2.5	5	10	MΩ
Thermal Resistance (Junction to Case)	θ _{JC}	SOT-23-3		74		°C/W
		SOT-23-5		74		



HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

AP2121

Electrical Characteristics (Continued)

AP2121-3.2 Electrical Characteristics

(V_{IN}=4.2V, T_J=25°C, C_{IN}=1μF, C_{OUT}=1μF, **Bold** typeface applies over -40°C≤T_J≤85°C, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	V _{OUT}	V _{IN} =4.2V 1mA≤I _{OUT} ≤30mA	3.136	3.2	3.264	V
Input Voltage	V _{IN}				6	V
Output Current	I _{OUT}	V _{IN} -V _{OUT} =1V	200			mA
Load Regulation	V _{RLOAD}	V _{IN} =4.2V 1mA≤I _{OUT} ≤80mA		12	40	mV
Line Regulation	V _{RLINE}	3.7V≤V _{IN} ≤6V I _{OUT} =30mA		4	16	mV
Dropout Voltage	V _{DROP}	I _{OUT} =10mA		20	40	mV
		I _{OUT} =100mA		150	300	
		I _{OUT} =150mA		200	400	
		I _{OUT} =200mA		250	500	
Quiescent Current	I _Q	V _{IN} =4.2V, I _{OUT} =0mA		25	50	μA
Standby Current	I _{STD}	V _{IN} =4.2V V _{CE} in OFF mode		0.1	1	μA
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p, f=1kHz V _{IN} =4.2V		70		dB
Output Voltage Temperature Coefficient	ΔV _{OUT} /ΔT	I _{OUT} =30mA		±320		μV/°C
	(ΔV _{OUT} /V _{OUT})/ΔT			±100		ppm/°C
Short Current Limit	I _{LIMIT}	V _{OUT} =0V		50		mA
RMS Output Noise	V _{NOISE}	T _A =25°C 10Hz ≤f≤100kHz		30		μVrms
CE "High" Voltage		CE input voltage "High"	1.5			V
CE "Low" Voltage		CE input voltage "Low"			0.25	V
CE Pull-down Resistance	R _{PD}		2.5	5	10	MΩ
Thermal Resistance (Junction to Case)	θ _{JC}	SOT-23-3		74		°C/W
		SOT-23-5		74		



HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

AP2121

Electrical Characteristics (Continued)

AP2121-3.3 Electrical Characteristics

(V_{IN}=4.3V, T_J=25°C, C_{IN}=1μF, C_{OUT}=1μF, **Bold** typeface applies over -40°C≤T_J≤85°C, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	V _{OUT}	V _{IN} =4.3V 1mA≤I _{OUT} ≤30mA	3.234	3.3	3.366	V
Input Voltage	V _{IN}				6	V
Output Current	I _{OUT}	V _{IN} -V _{OUT} =1V	200			mA
Load Regulation	V _{RLOAD}	V _{IN} =4.3V 1mA≤I _{OUT} ≤80mA		12	40	mV
Line Regulation	V _{RLINE}	3.8V≤V _{IN} ≤6V I _{OUT} =30mA		4	16	mV
Dropout Voltage	V _{DROP}	I _{OUT} =10mA		20	40	mV
		I _{OUT} =100mA		150	300	
		I _{OUT} =150mA		200	400	
		I _{OUT} =200mA		250	500	
Quiescent Current	I _Q	V _{IN} =4.3V, I _{OUT} =0mA		25	50	μA
Standby Current	I _{STD}	V _{IN} =4.3V V _{CE} in OFF mode		0.1	1	μA
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p, f=1kHz V _{IN} =4.3V		70		dB
Output Voltage Temperature Coefficient	ΔV _{OUT} /ΔT	I _{OUT} =30mA		±330		μV/°C
	(ΔV _{OUT} /V _{OUT})/ΔT			±100		ppm/°C
Short Current Limit	I _{LIMIT}	V _{OUT} =0V		50		mA
RMS Output Noise	V _{NOISE}	T _A =25°C 10Hz ≤f≤100kHz		30		μVrms
CE "High" Voltage		CE input voltage "High"	1.5			V
CE "Low" Voltage		CE input voltage "Low"			0.25	V
CE Pull-down Resistance	R _{PD}		2.5	5	10	MΩ
Thermal Resistance (Junction to Case)	θ _{JC}	SOT-23-3		74		°C/W
		SOT-23-5		74		

HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

AP2121

Typical Performance Characteristics

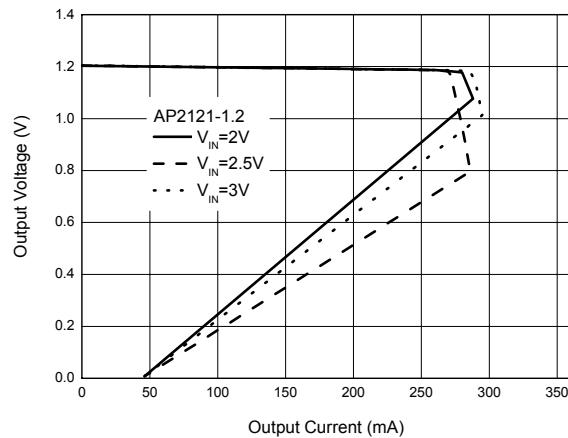


Figure 4. Output Voltage vs. Output Current

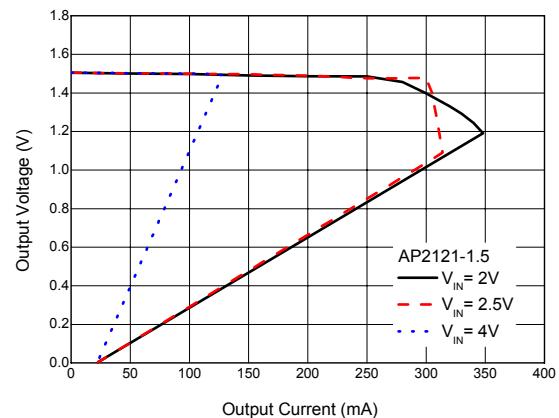


Figure 5. Output Voltage vs. Output Current

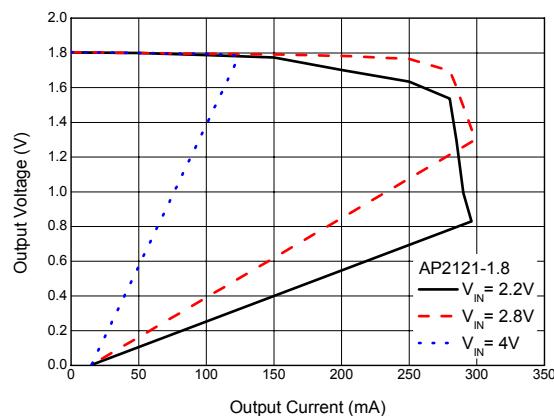


Figure 6. Output Voltage vs. Output Current

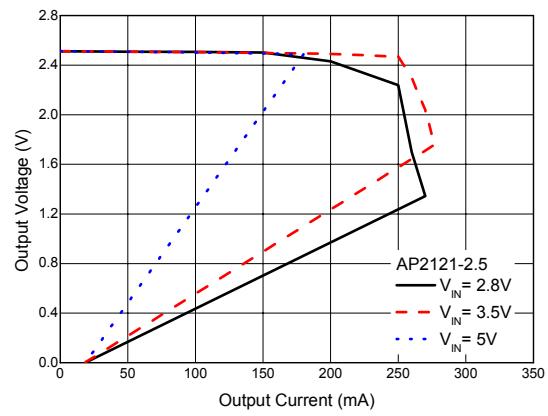


Figure 7. Output Voltage vs. Output Current

HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

AP2121

Typical Performance Characteristics (Continued)

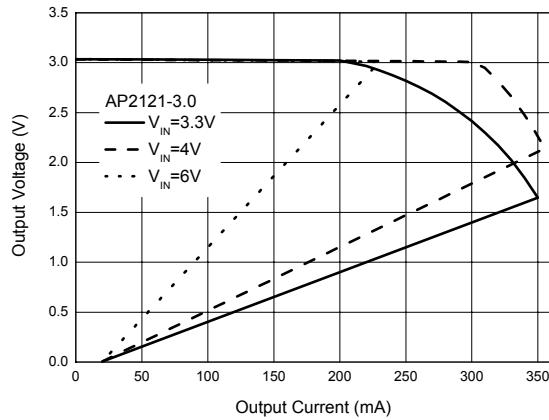


Figure 8. Output Voltage vs. Output Current

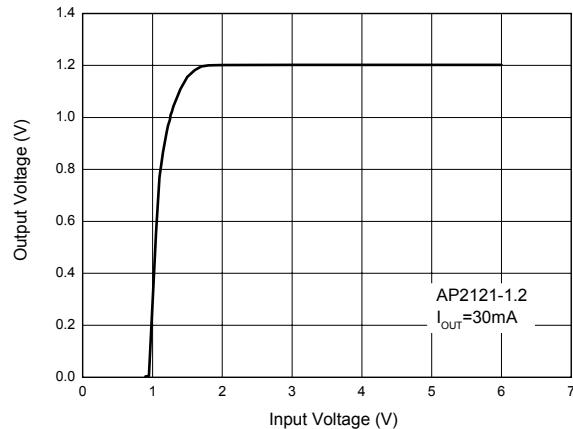


Figure 9. Output Voltage vs. Input Voltage

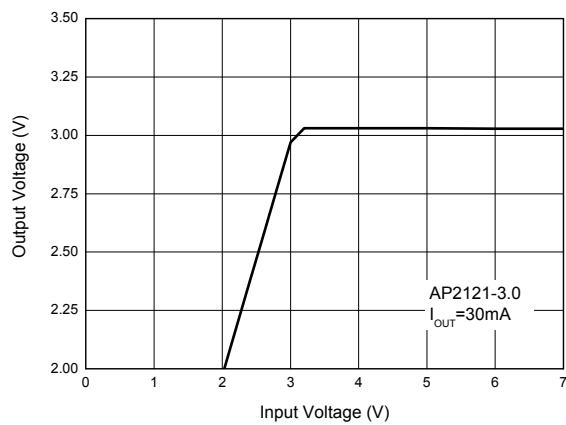


Figure 10. Output Voltage vs. Input Voltage

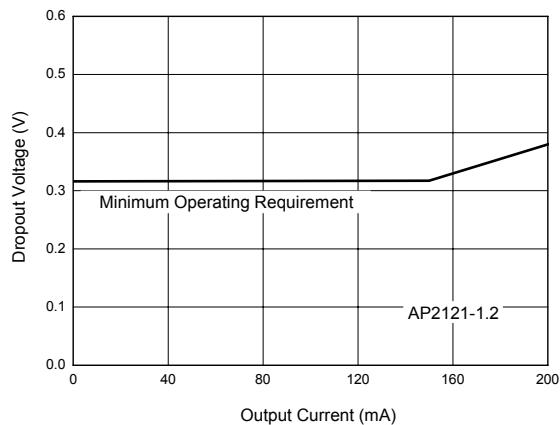


Figure 11. Dropout Voltage vs. Output Current

HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

AP2121

Typical Performance Characteristics (Continued)

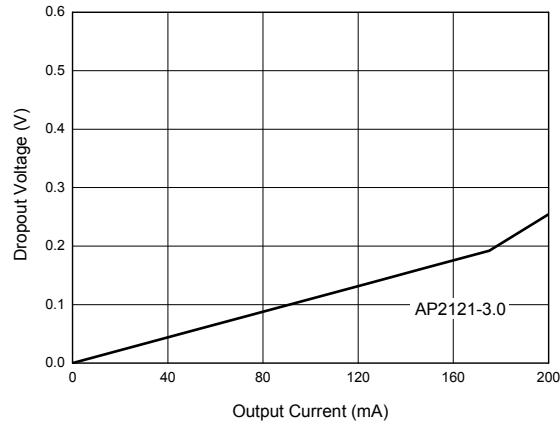


Figure 12. Dropout Voltage vs. Output Current

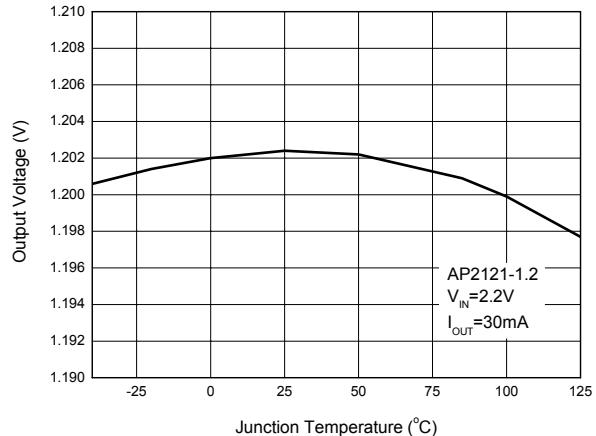


Figure 13. Output Voltage vs. Junction Temperature

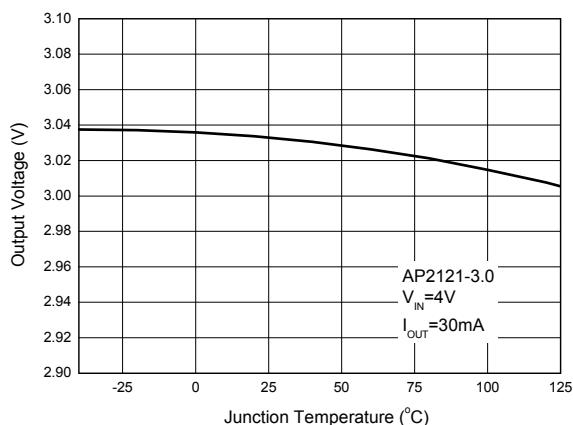


Figure 14. Output Voltage vs. Junction Temperature

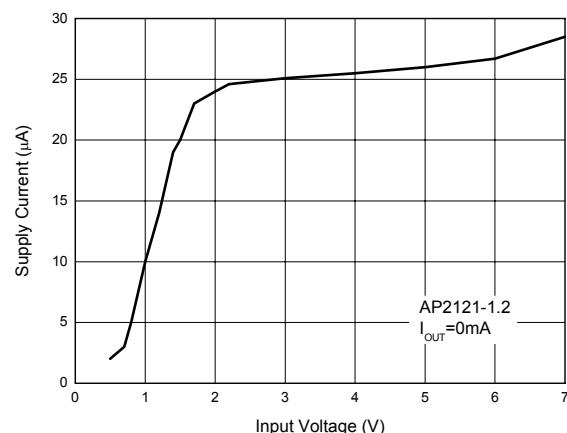


Figure 15. Supply Current vs. Input Voltage

HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

AP2121

Typical Performance Characteristics (Continued)

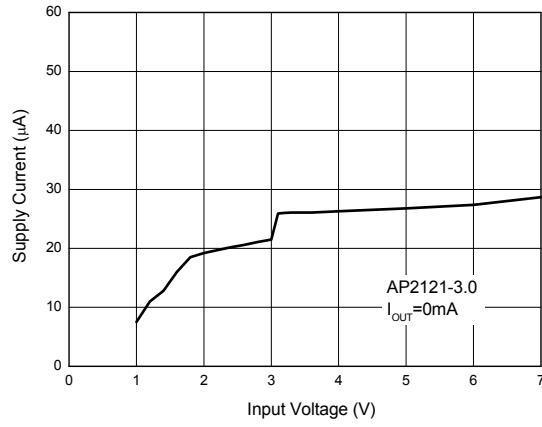


Figure 16. Supply Current vs. Input Voltage

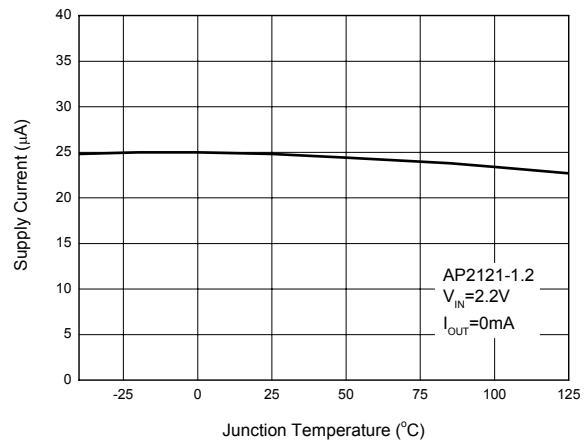


Figure 17. Supply Current vs. Junction Temperature

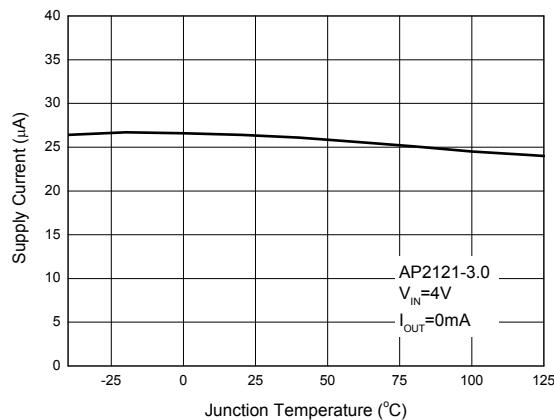


Figure 18. Supply Current vs. Junction Temperature

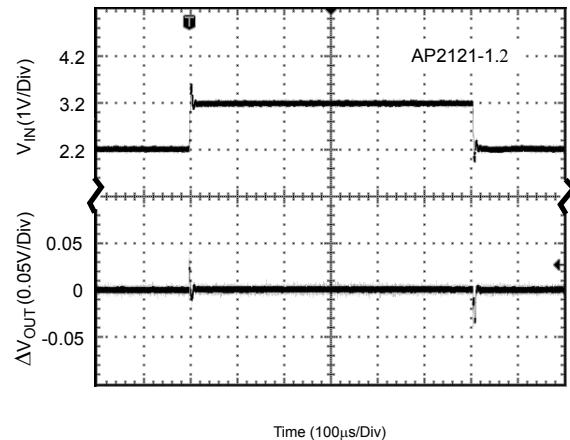


Figure 19. Line Transient
(Conditions: $I_{OUT}=30\text{mA}$, $C_{IN}=1\mu\text{F}$, $C_{OUT}=1\mu\text{F}$)

HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

AP2121

Typical Performance Characteristics (Continued)

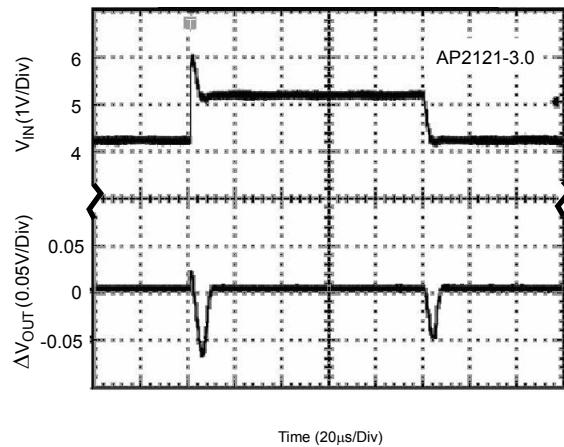


Figure 20. Line Transient
(Conditions: $I_{OUT}=30mA$, $C_{IN}=1\mu F$, $C_{OUT}=1\mu F$)

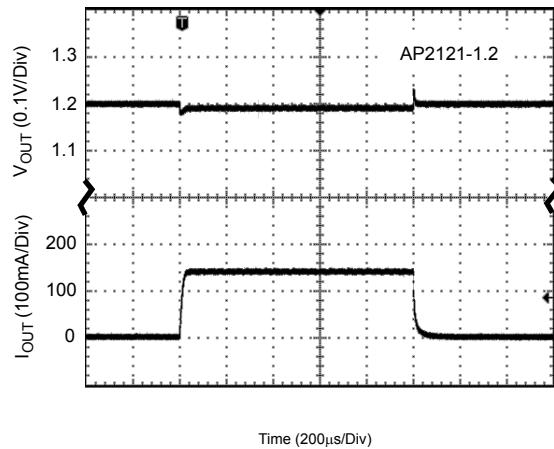


Figure 21. Load Transient
(Conditions: $V_{IN}=2.2V$, $C_{IN}=1\mu F$, $C_{OUT}=1\mu F$)

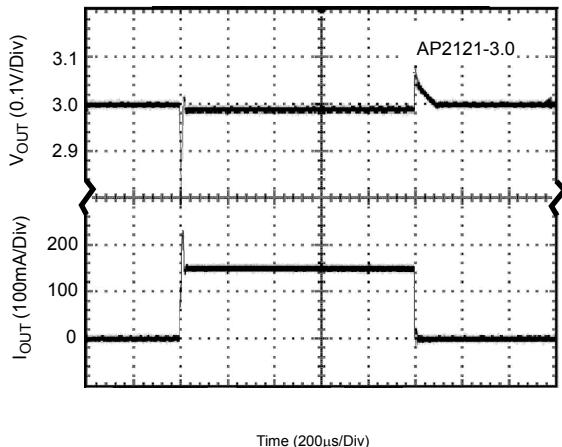


Figure 22. Load Transient
(Conditions: $V_{IN}=4V$, $C_{IN}=1\mu F$, $C_{OUT}=1\mu F$)

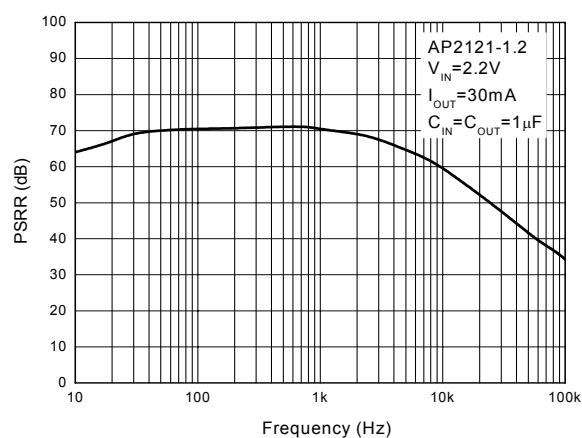


Figure 23. PSRR vs. Frequency

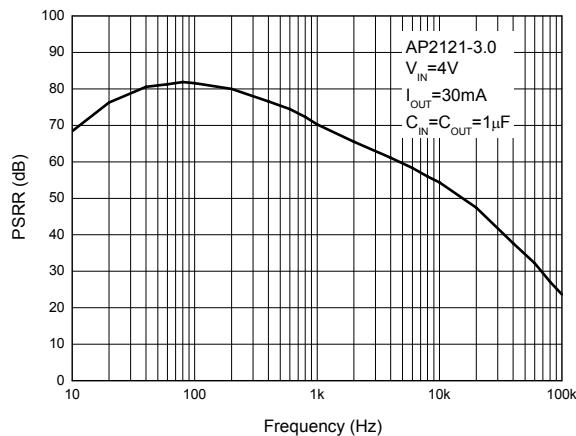
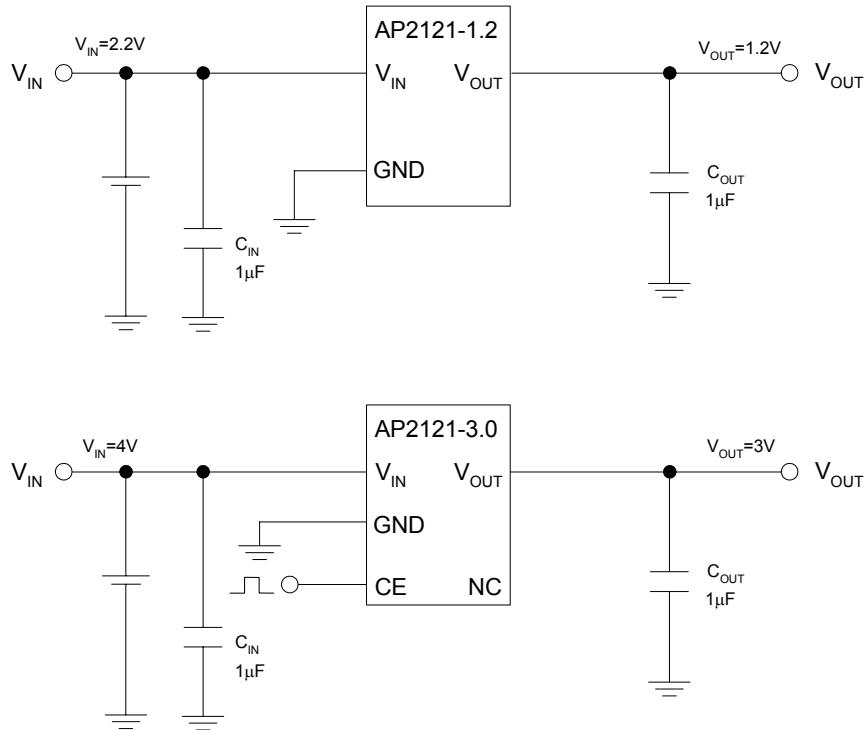
HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR**AP2121****Typical Performance Characteristics (Continued)**

Figure 24. PSRR vs. Frequency

HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

AP2121

Typical Application



Note: Filter capacitors are required at the AP2121's input and output. 1µF capacitor is required at the input. The minimum output capacitance required for stability should be more than 1µF with ESR from 0.01Ω to 100Ω. Ceramic capacitors are recommended.

Figure 25. Typical Application of AP2121

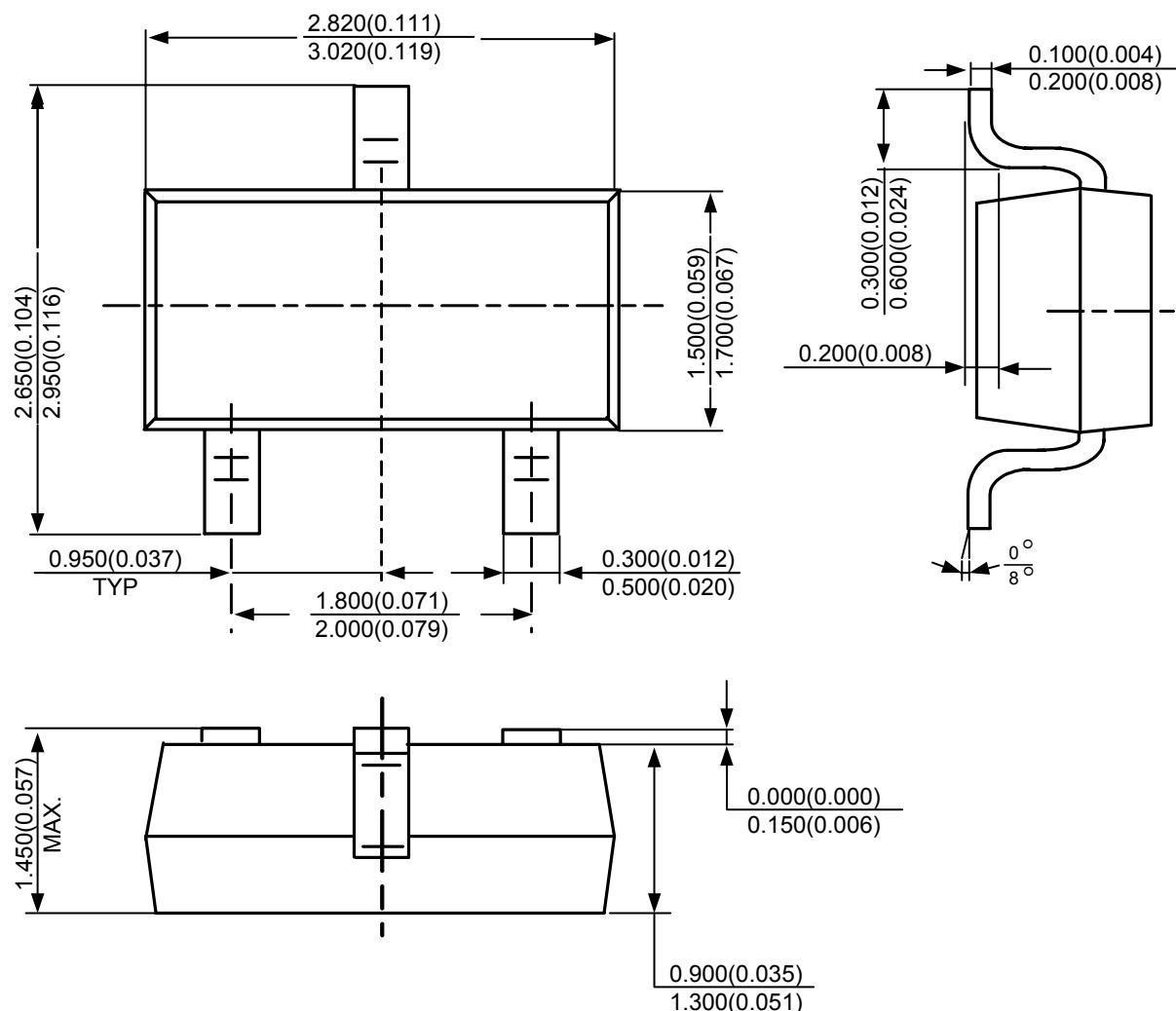
HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

AP2121

Mechanical Dimensions

SOT-23-3

Unit: mm(inch)



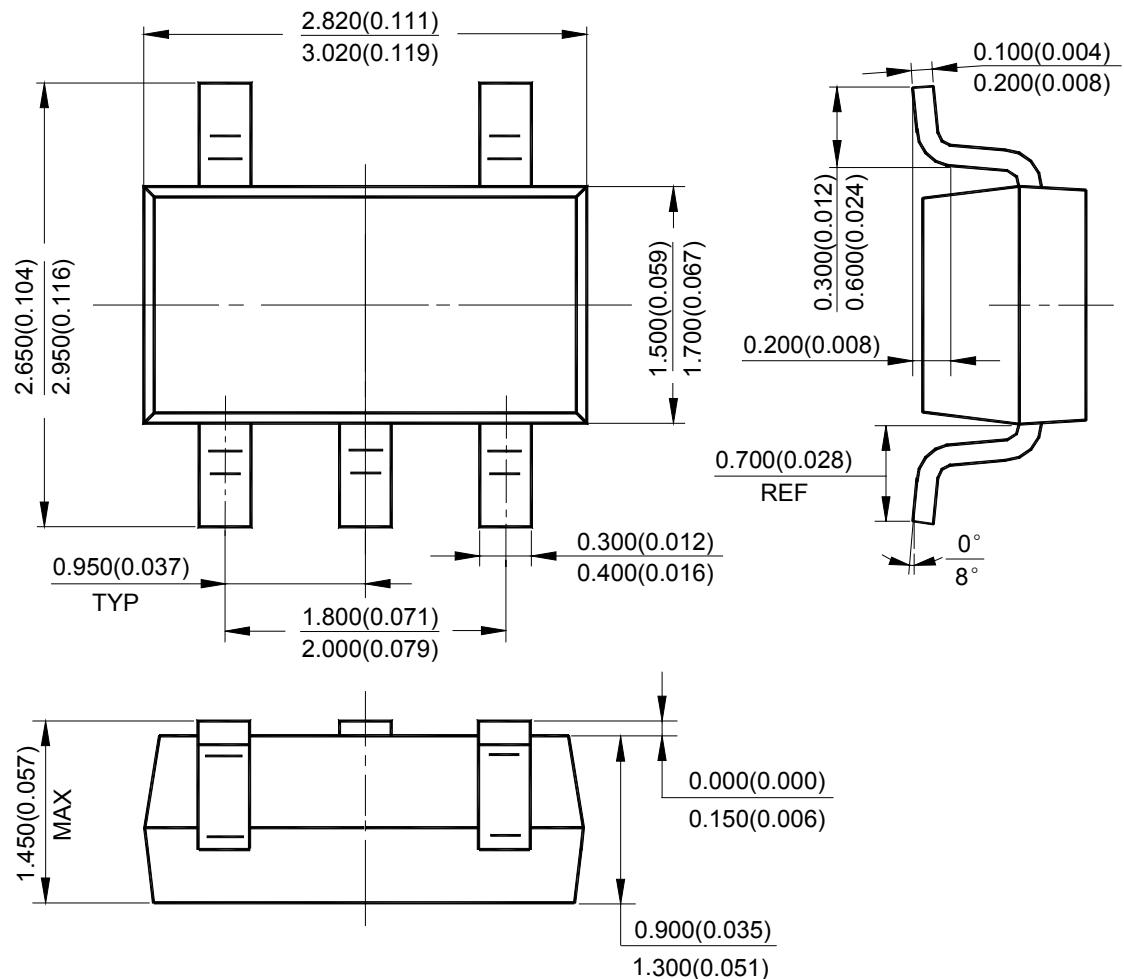
HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

AP2121

Mechanical Dimensions (Continued)

SOT-23-5

Unit: mm(inch)





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